

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE  
PATENT APPLICATION

In re Application of:

Visokay et al.

Serial No.: 10/674,771

Filed: 09/30/2003

For: MOS Transistor Gates with Doped Silicide and Methods for Making  
the Same



Atty. Docket: TI-35943

Art Unit: 2812

Examiner: V. Mandala

EXTENSION OF TIME

Commissioner for Patents

P. O. Box 1450

Alexandria, VA 22313-1450

CERTIFICATE OF MAILING OR TRANSMISSION

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage for First Class Mail in an envelope addressed to: Commissioner for Patents, Arlington, VA 22313-1450 or is being facsimile transmitted on the date indicated below:

12-10-04

Jackie McBride  
Jackie McBride

Sir:

Pursuant to 37 CFR 1.136(a), Applicant(s) respectfully petitions the Commissioner for an extension of the shortened statutory period in the above-referenced application.

The fee for this extension is indicated below:

X Two Month (\$450)

Please charge the fee to Deposit Account No. 20-0668. Any further necessary extension of time is hereby requested. Charge any additional fee or credit any overpayment to Deposit Account No. 20-0668. This paper is submitted in duplicate.

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Respectfully submitted,

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